

KSA1962

Audio Power Amplifier

- High Current Capability : I_C = 15A
- High Collector-Emitter Breakdown Voltage : BV_{CEO}=230V (Min.)
- High Power Dissipation
- Wide S.O.A
- Complement to KSC5242



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	-230	V
V _{CEO}	Collector-Emitter Voltage	-230	V
V_{EBO}	Emitter-Base Voltage	-5	V
I _C	Collector Current(DC)	-10	Α
I _B	Base Current	-1.5	Α
P _C	Collector Dissipation (T _C =25°C)	100	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 50 ~ 150	°C

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =-5mA, I _E =0	-230			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =-10mA, R _{BE} =∞	-230			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I_E =-5mA, I_C =0	-5			V
I _{CBO}	Collector Cut-off Current	V_{CB} =-230V, I_{E} =0			-5.0	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} =-5V, I _C =0			-5.0	μΑ
h _{FE1}	* DC Current Gain	V _{CE} =-5V, I _C =-1A	55		160	
h _{FE2}	DC Current Gain	V _{CE} =-5V, I _C =-7A	35	60		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =-8A, I _B =-0.8A		-0.4	-3.0	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} =-5V, I _C =-7A		-1.0	-1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =-5V, I _C =-1A		30		MHz
C _{ob}	Output Capacitance	V _{CB} =-10V, f=1MHz		360		pF
Pulse Test : PV	V=20us	-	•	•	•	•

* h_{FE} Classification

Classification	R	0	
h _{FE1}	55 ~ 110	80 ~ 160	

Typical Characteristics

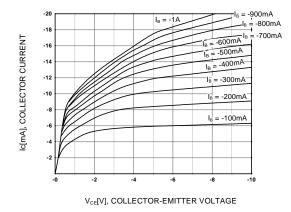


Figure 1. Static Characteristic

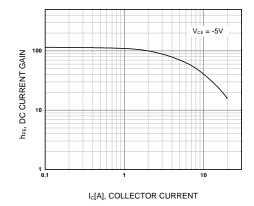


Figure 2. DC current Gain

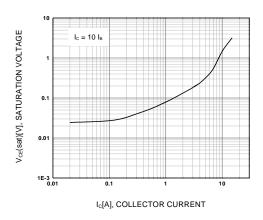


Figure 3. Collector-Emitter Saturation Voltage

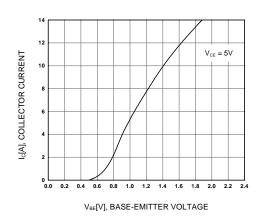


Figure 4. Collector Output Capacitance

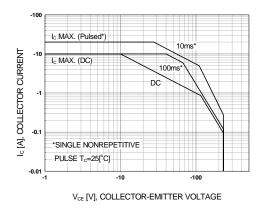


Figure 5. Safe Operating Area

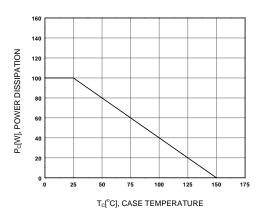
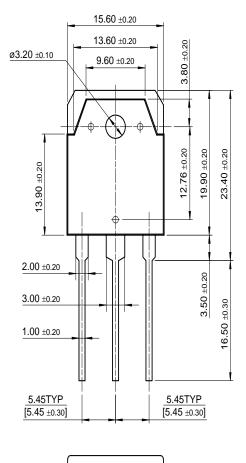


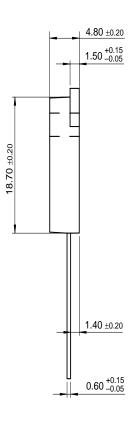
Figure 6. Power Derating

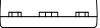
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Package Demensions

TO-3P







Dimensions in Millimeters

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